spiral inductor lspiral

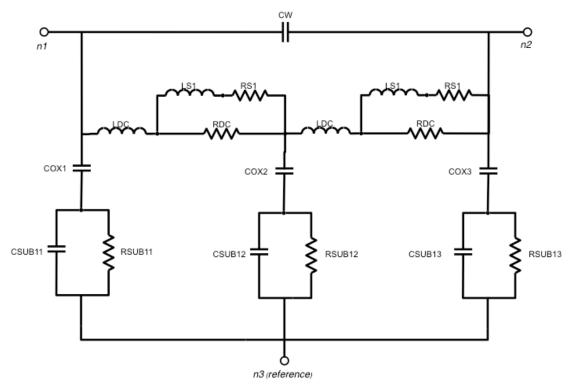


Figure 1: Lumped physical model of a wide-band distributed spiral inductor on silicon.

Form: lspiral:<instance name> n1 n2 n3 <parameter list> n1, n2, and n3 are the element terminals.

Terminal n3 is the element's reference terminal.

Parameters:

Parameter	Туре	Default value	Required?
rdc: low-frequency series resistance (Ω)	DOUBLE	n/a	yes
ldc: low-frequency series inductance (H)	DOUBLE	n/a	yes
rs1: frequency dependent resistance (Ω)	DOUBLE	n/a	yes
ls1: frequency dependent inductance (H)	DOUBLE	n/a	yes
ms1:mutual inductance between ldc and ls1 (H)	DOUBLE	n/a	yes
cw:capacitance between metal windings of inductor (F)	DOUBLE	n/a	yes
cox1: oxide capacitance (F)	DOUBLE	n/a	yes
csub11: substrate capacitance (F)	DOUBLE	n/a	yes
rsub11: substrate resistivity (Ω)	DOUBLE	n/a	yes
cox2: oxide capacitance (F)	DOUBLE	n/a	yes
csub21: substrate capacitance	DOUBLE	n/a	yes

rsub21: substrate resistivity (Ω)	DOUBLE	n/a	yes
cox3: oxide capacitance (F)	DOUBLE	n/a	yes
csub31: substrate capacitance (F)	DOUBLE	n/a	yes
rsub31: substrate resistivity (Ω)	DOUBLE	n/a	yes

- 1. cox_n , $rsub_{nm}$ and $csub_{nm}$ are process dependent parameters.
- 2. The other parameters may obtained analytically or using an appropriate extraction procedure [1], [2].

Example: Planar 9.5-nH spiral inductor [1]

 $lspiral:ls1\ 1\ 2\ 0\ rdc=2.778\ ldc=4.325e-9\ rs1=26e3\ ls1=le-6\ ms1=13.61e-9$

- + cw = 10.00e 15 cox 1 = 19.71e 15 csub11 = 64.67e 15 rsub11 = 101 cox 2 = 73.01e 15 rsub
- + csub21=10.82e-15 rsub21=457 cox3=15.27e-15 csub31=31.06e-15
- + rsub31=594

Details:

Example of transient analysis for a parallel RLC tank using a 9.5-nH planar spiral inductor

netlist file:

```
* Ispiral transient analysis
.options verbose
.options gsub11=9.90e-3 gsub21=2.189e-3 gsub31=1.688e-3
.tran2 tstop=1n tstep=4e-13 out_steps=100
```

isource:isrc 0 1 iac=1m f=8.8GHz

* RLC tank - capacitor value ignores non-idealities resistor:RL 1 0 r=1k capacitor:CL 1 0 c={1/(9.5e-9*(8.8GHz*2*pi)**2)} lspiral:ls1 1 0 0 rdc=2.778 ldc=4.325e-9 rs1=26e3 ls1=1e-6 ms1=13.61e-9 + cw=10.00e-15 cox1=19.71e-15 csub11=64.67e-15 rsub11={1/gsub11} cox2=73.01e-15 + csub21=10.82e-15 rsub21={1/gsub21} cox3=15.27e-15 csub31=31.06e-15 + rsub31={1/gsub31}

.options gnuplot

.options preamble="set title 'Parallel RLC Tank: 9.5-nH Planar spiral inductor'; set zero 1e-15; set grid; set data style lines; set xlabel 'Time (s)'; set key noautotitles; set ylabel 'Tank Voltage (V)'; set yrange [-0.8:0.8]"

.out plot term "1" vt preamble in "lsp_tr.dat"

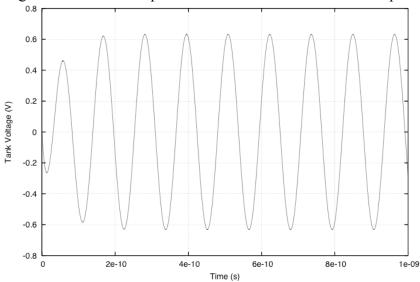
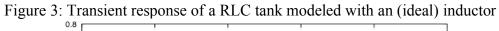
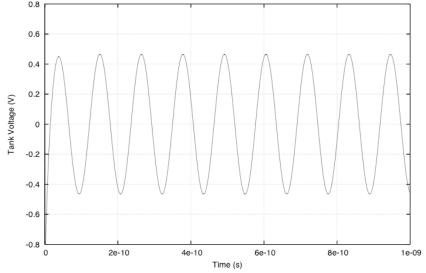


Figure 2: Transient response of a RLC tank modeled with Ispiral





Example of ac analysis for extracting inductor's quality factor from the short circuit admittance parameter (Y11):

netlist file:

* lspiral ac analysis .options verbose .options zo=50 .options gsub11=9.90e-3 gsub21=2.189e-3 gsub31=1.688e-3 .ac start=100e6 stop=10GHz n_freqs=10000

lspiral:ls1 1 2 0 rdc=2.778 ldc=4.325e-9 rs1=26e3 ls1=1e-6 ms1=13.61e-9

- $+ cw = 10.00e 15 cox 1 = 19.71e 15 csub11 = 64.67e 15 rsub11 = {1/gsub11} cox2 = 73.01e 15$
- + csub21=10.82e-15 rsub21={1/gsub21} cox3=15.27e-15 csub31=31.06e-15
- + rsub31={1/gsub31}

options gnuplot

options preamble="set title 'Q11: 9.5-nH Planar spiral inductor'; set zero 1e-15; set grid; set data style lines; set yrange [0:20]; set ylabel 'Q11'; set xrange [100e6:10e9]; set xlabel 'Frequency (Hz)'; set key noautotitles; Q(a,b)=(-b/a)"

.options postamble="using 1:(Q(\$2,\$3))"

* yll - short output, measure il/vl

out plot element "vsource:vin" O if -1 mult term "1" vf div postamble preamble in "y11.dat".

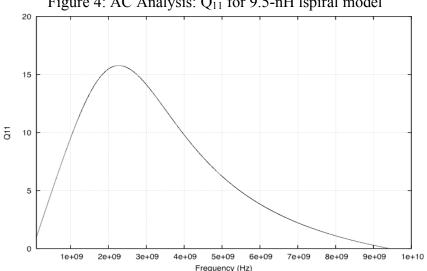


Figure 4: AC Analysis: Q₁₁ for 9.5-nH lspiral model

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Affiliation

Date

Links

References:

[1] A comprehensive compact-modeling methodology for spiral inductors in siliconbased RFICs, Watson, A.C.; Melendy, D.; Francis, P.; Kyuwoon Hwang; Weisshaar, A. Microwave Theory and Techniques, IEEE Transactions on On page(s): 849-857, Volume: 52, Issue: 3, March 2004

[2] Frequency-independent equivalent-circuit model for on-chip spiral inductors Yu Cao; Groves, R.A.; Xuejue Huang; Zamdmer, N.D.; Plouchart, J.-O.; Wachnik, R.A.; Tsu-Jae King; Chenming Hu; Solid-State Circuits, IEEE Journal of Volume 38, Issue 3, March 2003 Page(s):419 - 426